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Attorney's Docket No. 042390.P5769

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

GANG BAI

Serial No. 09/109,261

Filed: June 30, 1998

For: A MULTI-LAYER GATE DIELECTRIC

Examiner: Warren, M.

Art Group: 2815

RESPONSE TO FINAL OFFICE ACTION

Assistant Commissioner for Patents
Box Non-Fee Amendment
Washington, D.C. 20231

Dear Sir:

In response to the Final Office Action mailed August 13, 2001, in connection with the above-referenced patent application, the Applicant respectfully requests reconsideration in view of the following remarks. In this response, claims 8, 12, 15 and 19 have been amended. Accordingly, claims 8-21 are pending.

IN THE CLAIMS

Please admit the amendments of claims 8, 12, 15 and 19 below. It is believed these amendments put the claims in better form for allowance and comply with the requirements of 37 C.F.R., §1.116. Presented below are all pending claims, whether or not amended, in clean unmarked form. The claims in marked-up form are presented as an attachment.

Sub C
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(~~Three Times Amended~~) A transistor device having a gate electrode overlying a gate dielectric formed directly on a semiconductor substrate, the gate dielectric comprising: